

April 1988

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FAIRCHIL

SEMICONDUCTOR

74F37 **Quad Two-Input NAND Buffer**

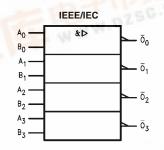
General Description

This device contains four independent gates, each of which performs the logic NAND function.

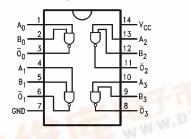
Ordering Code:

Order Number	Package Number	Package Description				
74F37SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow				
74F37SJ M14D		14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
74F37PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide				
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.						

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}		
A _n , B _n	Inputs	1.0/2.0	$20~\mu\text{A/}{-}1.2~\text{mA}$		
Ōn	Outputs	600/106.6 (80)	-12 mA/64 mA (48 mA)		

Inp	Output	
А	В	0
L	L	Н
L	н	Н

L

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⁷4F37 Quad Two-Input NAND Buffer

H = HIGH Voltage Level L = LOW Voltage Level

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Function Table



Н

L.

Absolute Maximum Ratings(Note 1)

Storage Temperature	$-65^{\circ}C$ to $+150^{\circ}C$
Ambient Temperature under Bias	$-55^{\circ}C$ to $+125^{\circ}C$
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with $V_{CC} = 0V$)	
Standard Output	-0.5V to V _{CC}
3-STATE Output	-0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated $I_{OL} \mbox{(mA)}$

Recommended Operating Conditions

Free Air Ambient Temperature	$0^{\circ}C$ to $+70^{\circ}C$
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

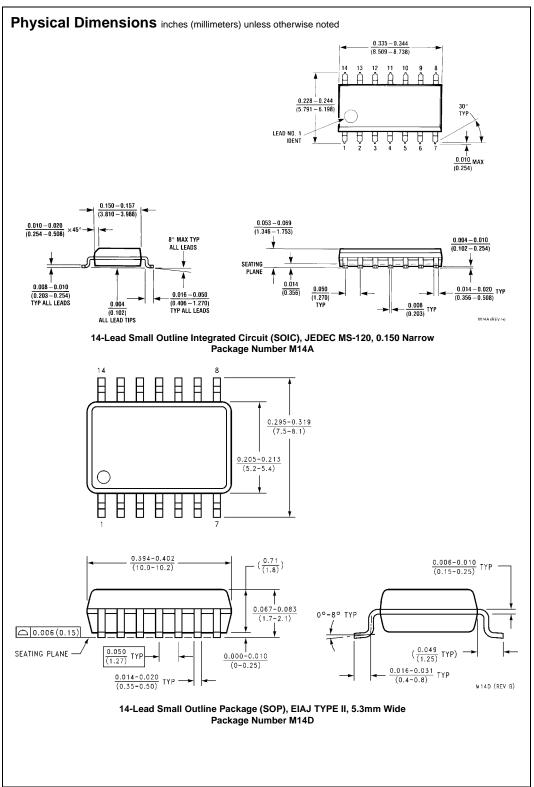
Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

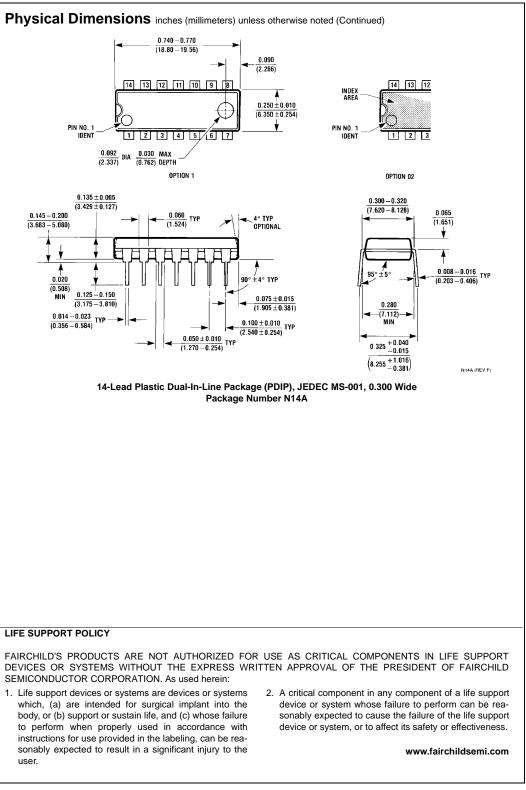
Symbol	Parameter		Parameter Min		Тур	Max	Units	V _{cc}	Conditions	
VIH	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal		
VIL	Input LOW Voltage				0.8	V		Recognized as a LOW Signal		
V _{CD}	Input Clamp Diode Voltage				-1.2	V	Min	I _{IN} = -18 mA		
V _{OH}	Output HIGH	10% V _{CC}	2.4					I _{OH} = -3 mA		
	Voltage	10% V _{CC}	2.0			V	Min	$I_{OH} = -15 \text{ mA}$		
		5% V _{CC}	2.7					$I_{OH} = -3 \text{ mA}$		
V _{OL}	Output LOW	10% V _{CC}			0.55	V	Min	I _{OL} = 64 mA		
	Voltage									
I _{IH}	Input HIGH				5.0	μA	Max	V _{IN} = 2.7V		
	Current									
I _{BVI}	Input HIGH Current				7.0	μA	Max	V _{IN} = 7.0V		
	Breakdown Test									
ICEX	Output HIGH				50	μA	Max	$V_{OUT} = V_{CC}$		
	Leakage Current									
V _{ID}	Input Leakage		4.75			V	0.0	I _{ID} = 1.9 μA		
	Test							All Other Pins Grounded		
I _{OD}	Output Leakage				3.75	μA	0.0	V _{IOD} = 150 mV		
	Circuit Current							All Other Pins Grounded		
IIL	Input LOW Current				-1.2	mA	Max	$V_{IN} = 0.5V$		
l _{os}	Output Short-Circuit Current		-100		-225	mA	Max	$V_{OUT} = 0V$		
I _{CCH}	Power Supply Current			3.7	6.0	mA	Max	V _O = HIGH		
ICCL	Power Supply Current			28.0	33.0	mA	Max	$V_{O} = LOW$		

AC Electrical Characteristics

			$T_A = +25^{\circ}C$		$T_A = 0^{\circ}C$ to $+70^{\circ}C$		
Symbol	Parameter	$V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			C _L = 50 pF		Units
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	2.0	3.2	5.5	1.5	6.5	ns
t _{PHL}	$A_n, B_n \text{ to } \overline{O}_n$	1.5	2.4	4.5	1.0	5.0	



74F37



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